Vishay Semiconductors

High Performance Schottky Rectifier, 3 A

Anode

-0



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SMC

PRODUCT SUMMARY			
Package	SMC		
I _{F(AV)}	3.0 A		
V _R	100 V		
V _F at I _F	0.62 V		
I _{RM}	5 mA at 125 °C		
T _J max.	175 °C		
Diode variation	Single die		
E _{AS}	3.0 mJ		

FEATURES

• Low forward voltage drop



RoHS

COMPLIANT

HALOGEN

FREE

- Guard ring for enhanced ruggedness and long term reliability
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-30BQ100-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS VALUES U		UNITS	
I _{F(AV)}	Rectangular waveform	3.0	А	
V _{RRM}		100	V	
I _{FSM}	$t_p = 5 \ \mu s \ sine$	800	А	
V _F	3.0 A _{pk} , T _J = 125 °C	0.62	V	
TJ	Range	-55 to +175	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-30BQ100-M3	UNITS	
Maximum DC reverse voltage	V _R	100	V	
Maximum working peak reverse voltage	V _{RWM}	100	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average ferward average		50 % duty cycle at T_L = 148 °C, rectangular waveform		3.0	
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_L = 138 °C, rectangular waveform		4.0	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	800	A
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	70	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.0 A, L = 6 mH		3.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.5	А

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V _{FM} ⁽¹⁾	3 A	T _J = 25 °C	0.79	V
Maximum forward voltage drop		6 A		0.90	
Maximum forward voltage drop		3 A	- T _J = 125 °C	0.62	
		6 A		0.70	
Manimum manager la classe a summer la	1	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.5	mA
Maximum reverse leakage current	I _{RM}	T _J = 125 °C	VR = naleu VR	5.0	ШA
Maximum junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		115	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		3.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 00		10 000	V/µs

Note

⁽¹⁾ Pulse width = 300 μ s, duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +175	°C
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾		12	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	46	
Approvimeto weight			0.24	g
Approximate weight			0.008	oz.
Marking device		Case style SMC (similar to DO-214AB) 3J		J

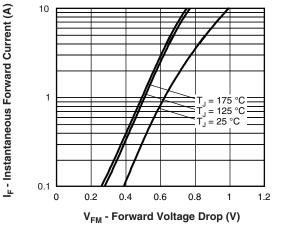
Notes

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink (1)

(2) Mounted 1" square PCB

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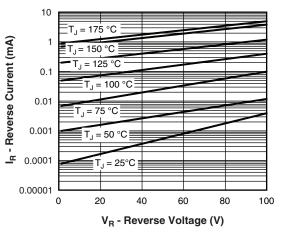
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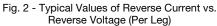


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Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





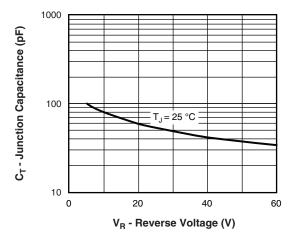


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

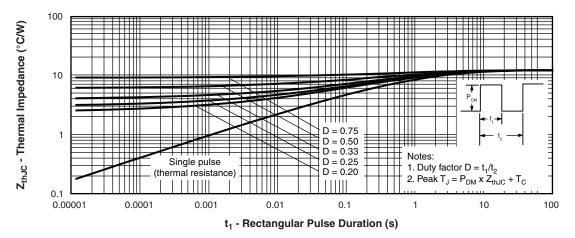
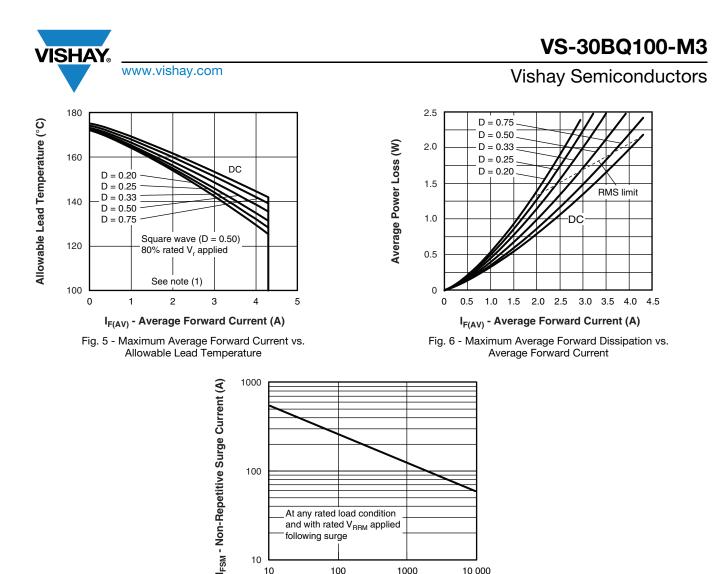


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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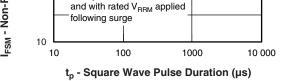


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

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<sup>(1)</sup> Formula used: T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};

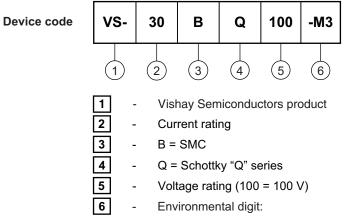
Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D) (see fig. 6);

Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D); I_R at V_{R1} = 80 \% rated V_R
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ORDERING INFORMATION TABLE



-M3 = Halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-30BQ100-M3/9AT	9AT	3500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95402				
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			

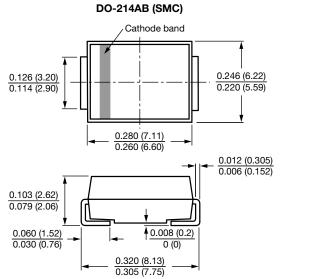


Outline Dimensions

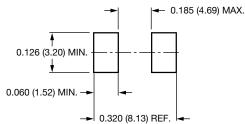
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DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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